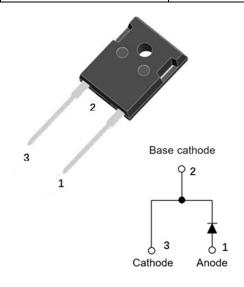
Silicon Carbide Schottky Diode

V_{RRM}	1200V
I _{F 135°C}	20A
Q _C	53nC



Features

Positive temperature coefficient

Temperature-independent switching

Maximum working temperature at 175 °C

Unipolar devices and zero reverse recovery current

Zero forward recovery current

Essentially no switching losses

Reduction of heat sink requirements

High-frequency operation

Reduction of EMI

Typical Applications

Typical applications are in power factor correction(PFC), solar inverter, uninterruptible power supply, motor drives, photovoltaic inverter, electric car and charger.

Mechanical Data

Package: TO-247AC

Terminals: Tin plated leads

Polarity: As marked

Maximum Ratings (T_C=25 Unless otherwise specified

PARAMTETER	SYMBOL	UNIT	VALUE
Device marking code			D112010NQG2
Reverse voltage (repetitive peak) @ T _j =25°C	V_{RRM}	V	1200
Reverse voltage (Surge Peak) @ T _j =25°C	V_{RSM}	V	1200
Reverse voltage (DC) @ T _j =25°C	V _{DC}	V	1200
Continuous forward current @ T _c =25°C T _c =135°C T _c =163°C	I _F	Α	40 20 10
Non-repetitive peak forward surge current @ T _c =25°C, tp=10ms, Half Sine Wave	I _{FSM}	А	85
Power Dissipation@ T _c =25°C T _c =110°C	P _{TOT}	W	266 115
i²t Value@ Tc=25°C ,tp=10ms	i²dt	A ² S	36
Operating junction and Storage temperature range	T_{j} , T_{stg}	°C	-55 to +175

Electrical Characteristics

PARAMTETER	SYMBOL	UNIT	TEST CONDITIONS	Тур.	Max.								
Forward voltage drap	V _F	V	I _F =10A, T _j =25°C	1.42	1.54								
Forward voltage drop			I _F =10A, T _j =175°C	2.1									
Povorce leekage gurrent	I _R			V _R =1200V, T _j =25°C	1.3	13							
Reverse leakage current			V _R =1200V, T _j =175°C	6									
Total capacitive charge	Qc	nC	$V_R=800V, T_j=25^{\circ}C, _{0}^{VR}C(V)dV$	53									
	С	С	С								V _R =0V, f=1MHZ	700	
Total capacitance				C pF	V _R =400V, f=1MHZ	49							
			V _R =800V, f=1MHZ	39									
Capacitance Stored Energy	Ec		V _R =800V	14									

Thermal Characteristics T_a=25 Unless otherwise specified

PARAMETER	SYMBOL	UNIT	VALUE
Thermal resistance	R _{-C}	°C W	0.56

Characteristics (Typical)

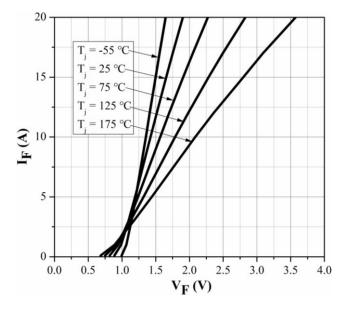


Figure 1. Forward Characteristics

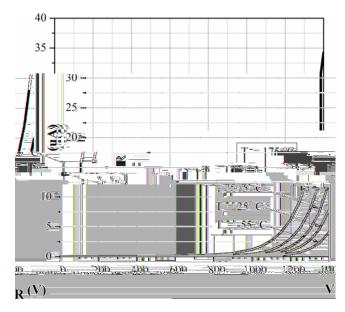


Figure 2. Reverse Characteristic

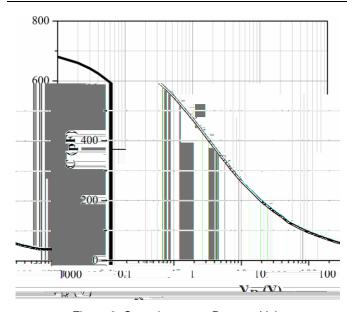


Figure 3. Capacitance vs. Reverse Voltage

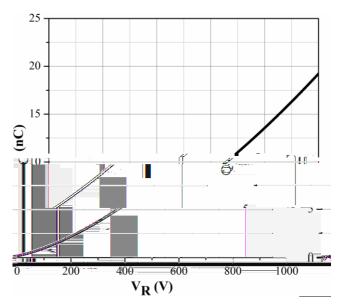
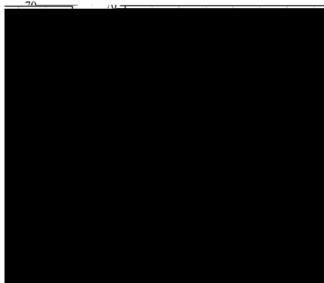


Figure 4. Total Capacitance Charge vs. Reverse Voltage



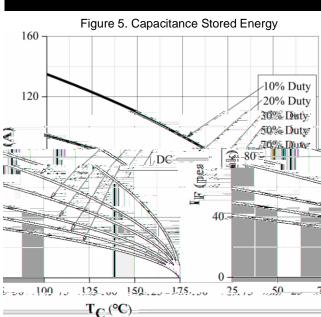


Figure 7. Current Derating

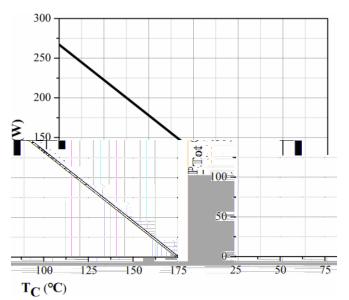


Figure 6. Power Derating

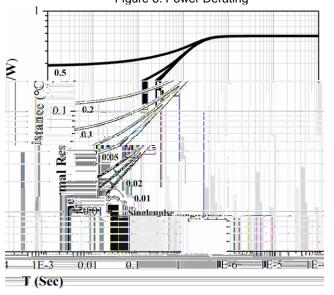


Figure 8. Transient Thermal Impedance



Outline Dimensions

TO247-AC				
Dim	Min	Max		
Α	4.80	5.20		
A1	2.21	2.61		



Disclaimer

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